

General Description

Renesas SLG7RN45708 is a low power and small form device. The SoC is housed in a 1.6mm x 1.6mm STQFN package which is optimal for using with small devices.

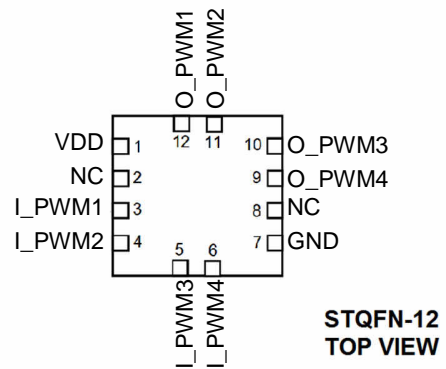
Features

- Low Power Consumption
- Pb - Free / RoHS Compliant
- Halogen - Free
- STQFN - 12 Package

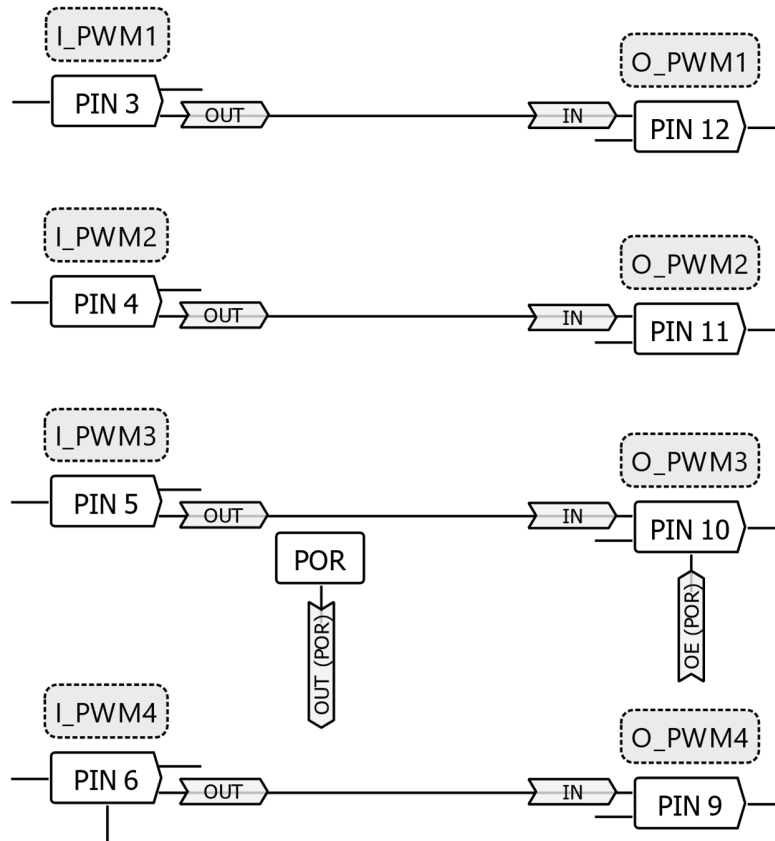
Output Summary

4 Outputs - Push Pull 2X

Pin Configuration



Block Diagram



Pin Configuration

| Pin # | Pin Name | Type | Pin Description | Internal Resistor |
|-------|----------|----------------|---------------------------------|-------------------|
| 1 | VDD | PWR | Supply Voltage | -- |
| 2 | NC | -- | Keep Floating or Connect to GND | -- |
| 3 | I_PWM1 | Digital Input | Low Voltage Digital Input | floating |
| 4 | I_PWM2 | Digital Input | Low Voltage Digital Input | floating |
| 5 | I_PWM3 | Digital Input | Low Voltage Digital Input | floating |
| 6 | I_PWM4 | Digital Input | Low Voltage Digital Input | floating |
| 7 | GND | GND | Ground | -- |
| 8 | NC | -- | Keep Floating or Connect to GND | -- |
| 9 | O_PWM4 | Digital Output | Push Pull 2X | floating |
| 10 | O_PWM3 | Digital Output | Push Pull 2X | floating |
| 11 | O_PWM2 | Digital Output | Push Pull 2X | floating |
| 12 | O_PWM1 | Digital Output | Push Pull 2X | floating |

Ordering Information

| Part Number | Package Type |
|----------------|-------------------------------------|
| SLG7RN45708V | V=STQFN-12 |
| SLG7RN45708VTR | STQFN-12 – Tape and Reel (3k units) |

Absolute Maximum Conditions

| Parameter | | Min. | Max. | Unit |
|---|--------------|------------|------------|------|
| Supply Voltage on VDD relative to GND | | -0.5 | 7 | V |
| DC Input Voltage | | GND - 0.5V | VDD + 0.5V | V |
| Maximum Average or DC Current (Through pin) | Push-Pull 2x | -- | 17 | mA |
| Current at Input Pin | | -1.0 | 1.0 | mA |
| Input leakage (Absolute Value) | | -- | 1000 | nA |
| Storage Temperature Range | | -65 | 150 | °C |
| Junction Temperature | | -- | 150 | °C |
| ESD Protection (Human Body Model) | | 2000 | -- | V |
| ESD Protection (Charged Device Model) | | 1000 | -- | V |
| Moisture Sensitivity Level | | 1 | | |

Electrical Characteristics

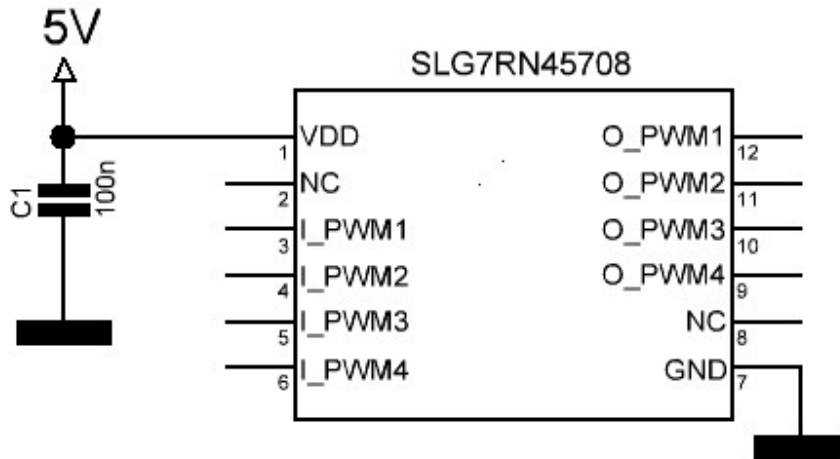
| Symbol | Parameter | Condition/Note | Min. | Typ. | Max. | Unit |
|------------------|---|-----------------------------------|-------|------|-------|------|
| V _{DD} | Supply Voltage | | 1.71 | 5 | 5.5 | V |
| T _A | Operating Temperature | | -40 | 25 | 85 | °C |
| C _{VDD} | Capacitor Value at VDD | | -- | 0.1 | -- | μF |
| C _{IN} | Input Capacitance | | -- | 4 | -- | pF |
| I _Q | Quiescent Current | PINs3,4,5,6 are LOW | -- | 1 | -- | μA |
| V _O | Maximal Voltage Applied to any PIN in High-Impedance State | | -- | -- | VDD | V |
| I _{VDD} | Maximum Average or DC Current Through VDD Pin (Per chip side, see Note 2) | T _J = 85°C | -- | -- | 73 | mA |
| I _{VDD} | Maximum Average or DC Current Through VDD Pin (Per chip side, see Note 2) | T _J = 110°C | -- | -- | 35 | mA |
| I _{GND} | Maximum Average or DC Current Through GND Pin (Per chip side, see Note 2) | T _J = 85°C | -- | -- | 92 | mA |
| I _{GND} | Maximum Average or DC Current Through GND Pin (Per chip side, see Note 2) | T _J = 110°C | -- | -- | 44 | mA |
| V _{IH} | HIGH-Level Input Voltage | Low-Level Logic Input at VDD=1.8V | 0.980 | -- | VDD | V |
| | | Low-Level Logic Input at VDD=3.3V | 1.130 | -- | VDD | V |
| | | Low-Level Logic Input at VDD=5.0V | 1.230 | -- | VDD | V |
| V _{IL} | LOW-Level Input Voltage | Low-Level Logic Input at VDD=1.8V | 0 | -- | 0.520 | V |
| | | Low-Level Logic Input at VDD=3.3V | 0 | -- | 0.690 | V |
| | | Low-Level Logic Input at VDD=5.0V | 0 | -- | 0.780 | V |

| | | | | | | |
|---------------------|------------------------------------|--|--------|--------|-------|----|
| V _{OH} | HIGH-Level Output Voltage | Push-Pull 2X, Open Drain PMOS 2X, I _{OH} =100μA, at VDD=1.8V | 1.700 | 1.800 | -- | V |
| | | Push-Pull 2X, Open Drain PMOS 2X, I _{OH} =3mA, at VDD=3.3V | 2.850 | 3.190 | -- | V |
| | | Push-Pull 2X, Open Drain PMOS 2X, I _{OH} =5mA, at VDD=5.0V | 4.320 | 4.860 | -- | V |
| V _{OL} | LOW-Level Output Voltage | Push-Pull 2X, I _{OL} =100μA, at VDD=1.8V | -- | 0.010 | 0.020 | V |
| | | Push-Pull 2X, I _{OL} =3mA, at VDD=3.3V | -- | 0.090 | 0.130 | V |
| | | Push-Pull 2X, I _{OL} =5mA, at VDD=5.0V | -- | 0.120 | 0.160 | V |
| I _{OH} | HIGH-Level Output Current (Note 1) | Push-Pull 2X, Open Drain PMOS 2X, V _{OH} =VDD-0.2V, at VDD=1.8V | 2.100 | 2.680 | -- | mA |
| | | Push-Pull 2X, Open Drain PMOS 2X, V _{OH} =2.4V, at VDD=3.3V | 11.460 | 19.610 | -- | mA |
| | | Push-Pull 2X, Open Drain PMOS 2X, V _{OH} =2.4V, at VDD=5.0V | 41.886 | 55.990 | -- | mA |
| I _{OL} | LOW-Level Output Current (Note 1) | Push-Pull 2X, V _{OL} =0.15V, at VDD=1.8V | 1.520 | 2.660 | -- | mA |
| | | Push-Pull 2X, V _{OL} =0.4V, at VDD=3.3V | 8.130 | 12.360 | -- | mA |
| | | Push-Pull 2X, V _{OL} =0.4V, at VDD=5.0V | 11.590 | 19.460 | -- | mA |
| T _{SU} | Startup Time | From VDD rising past 1.35 V | -- | 0.31 | -- | ms |
| PON _{THR} | Power On Threshold | V _{DD} Level Required to Start Up the Chip | 1.180 | 1.353 | 1.516 | V |
| POFF _{THR} | Power Off Threshold | V _{DD} Level Required to Switch Off the Chip | 0.730 | 0.914 | 1.103 | V |

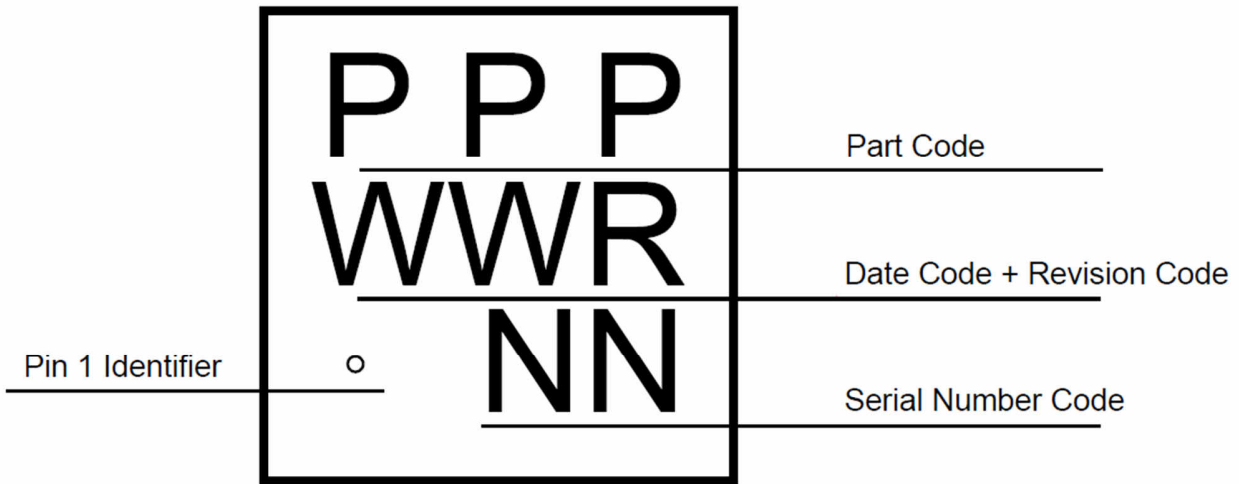
Note:

- DC or average current through any pin should not exceed value given in Absolute Maximum Conditions.
- The GreenPAK's power rails are divided in two sides. Pins 2, 3, 4, 5 and 6 are connected to one side, pins 8, 9, 10, 11 and 12 to another.
- Guaranteed by Design.

Typical Application Circuit



Package Top Marking

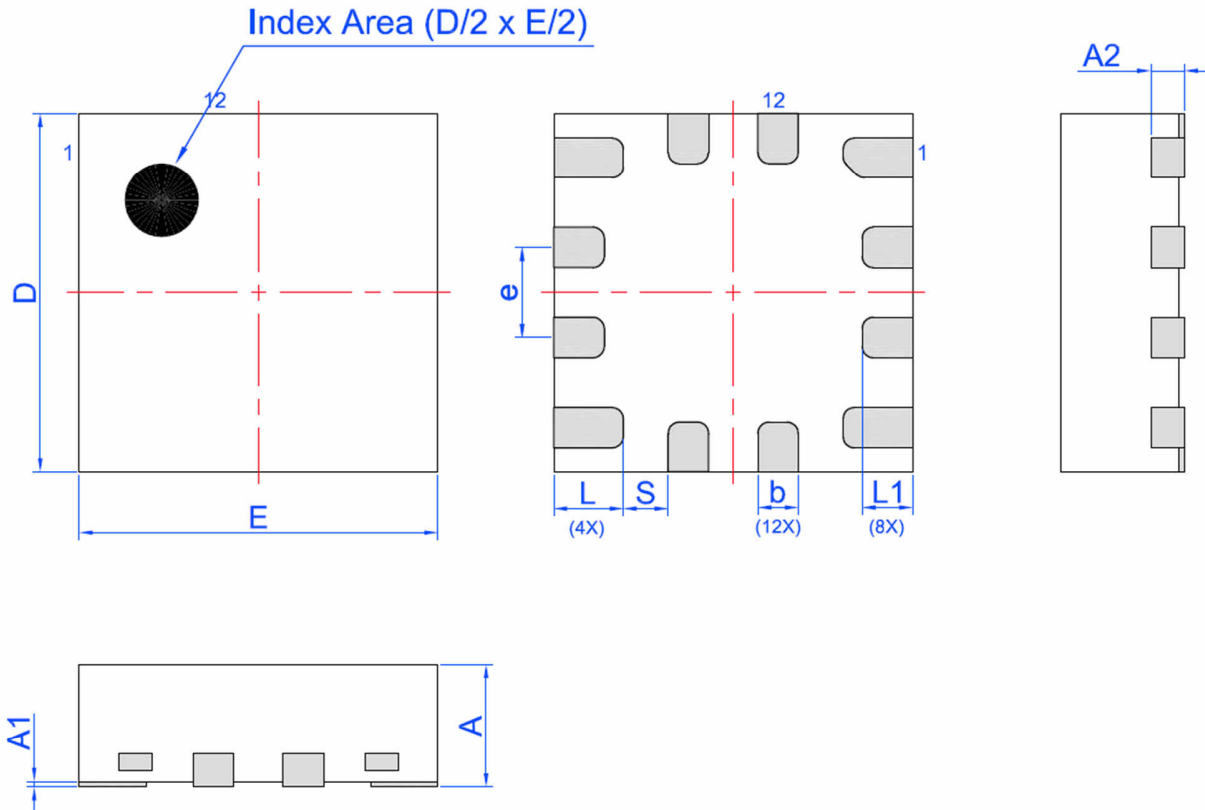


| Datasheet Revision | Programming Code Number | Lock Status | Checksum | Part Code | Revision | Date |
|--------------------|-------------------------|-------------|------------|-----------|----------|------------|
| 0.10 | 001 | L | 0x67022BC5 | | | 04/14/2022 |

The IC security bit is locked/set for code security for production unless otherwise specified. The Programming Code Number is not changed based on the choice of locked vs. unlocked status.

Package Drawing and Dimensions

12 Lead STQFN FCA Package 1.6 x 1.6 mm



Unit: mm

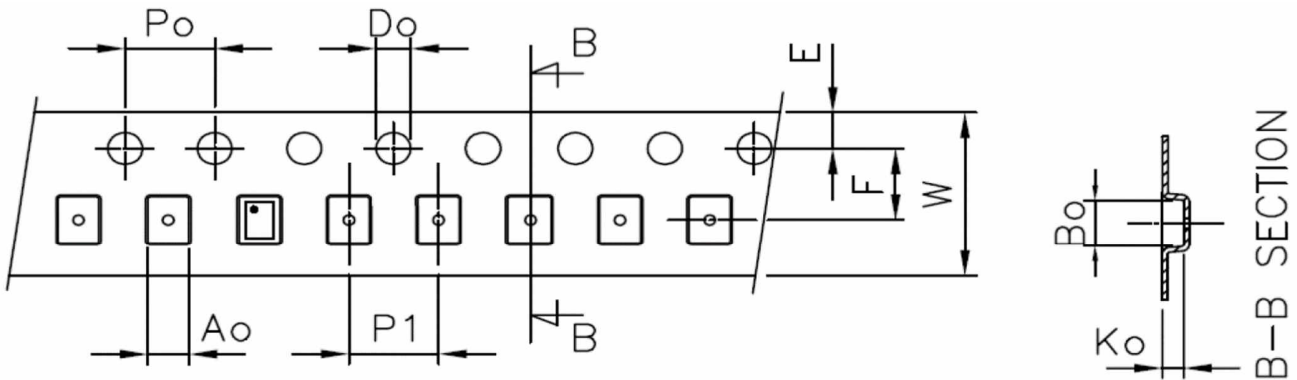
| Symbol | Min | Nom. | Max | Symbol | Min | Nom. | Max |
|--------|----------|------|-------|--------|---------|-------|-------|
| A | 0.50 | 0.55 | 0.60 | D | 1.55 | 1.60 | 1.65 |
| A1 | 0.005 | - | 0.060 | E | 1.55 | 1.60 | 1.65 |
| A2 | 0.10 | 0.15 | 0.20 | L | 0.26 | 0.31 | 0.36 |
| b | 0.13 | 0.18 | 0.23 | L1 | 0.175 | 0.225 | 0.275 |
| e | 0.40 BSC | | | S | 0.2 REF | | |

Tape and Reel Specification

| Package Type | # of Pins | Nominal Package Size [mm] | Max Units | | Reel & Hub Size [mm] | Leader (min) | | Trailer (min) | | Tape Width [mm] | Part Pitch [mm] |
|-----------------------------------|-----------|---------------------------|-----------|---------|----------------------|--------------|-------------|---------------|-------------|-----------------|-----------------|
| | | | per Reel | per Box | | Pockets | Length [mm] | Pockets | Length [mm] | | |
| STQFN 12L FCA 0.4P Green | 12 | 1.6x1.6x0.55 | 3000 | 3000 | 178/60 | 100 | 400 | 100 | 400 | 8 | 4 |

Carrier Tape Drawing and Dimensions

| Package Type | Pocket BTM Length | Pocket BTM Width | Pocket Depth | Index Hole Pitch | Pocket Pitch | Index Hole Diameter | Index Hole to Tape Edge | Index Hole to Pocket Center | Tape Width |
|--------------------------------|-------------------|------------------|--------------|------------------|--------------|---------------------|-------------------------|-----------------------------|------------|
| | A0 | B0 | K0 | P0 | P1 | D0 | E | F | W |
| STQFN 12L FCA 0.4P Green | 1.80±0.05 | 1.80±0.05 | ±0.7 | 4 | 4 | 1.5 | 1.75 | 3.5 | 8 |



Recommended Reflow Soldering Profile

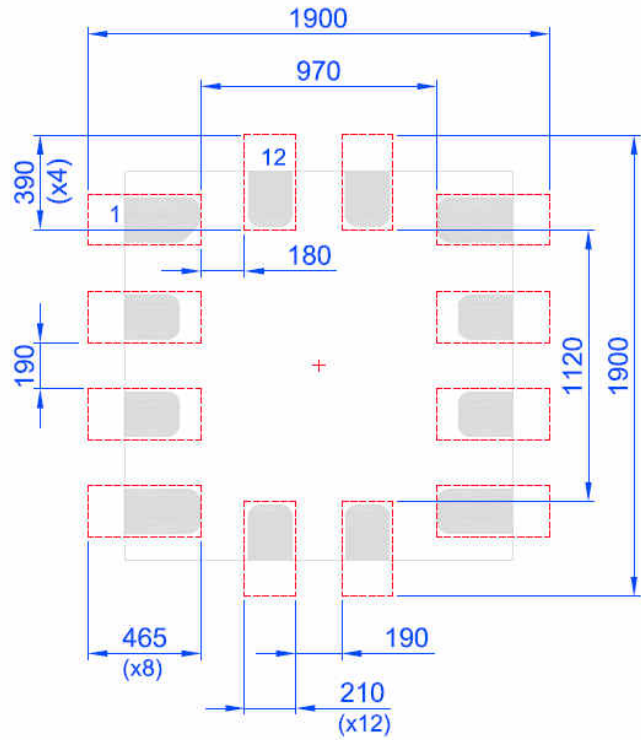
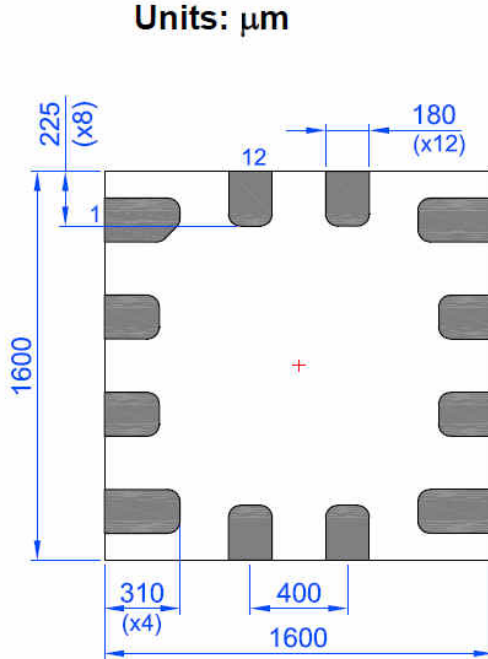
Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 1.408 mm³ (nominal). More information can be found at www.jedec.org.

Recommended Land Pattern

 Exposed Pad
(PKG face down)

 Recommended Land Pattern
(PKG face down)

Units: μm



Datasheet Revision History

| Date | Version | Change |
|-------------|----------------|------------------------------|
| 04/14/2022 | 0.10 | New design for SLG46120 chip |

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